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Kind regards,

Team Nexperia



BAT760 Medium power Schottky barrier single diode Rev. 03 – 17 October 2008

Product data sheet

1. Product profile

1.1 General description

Planar medium power Schottky barrier single diode with an integrated guard ring for stress protection, encapsulated in a SOD323 (SC-76) very small Surface-Mounted Device SMD plastic package.

1.2 Features

- Ultra high-speed switching
- Very low forward voltage
- Guard-ring protected
- Very small SMD plastic package

1.3 Applications

- Ultra high-speed switching
- Voltage clamping
- Protection circuits

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _R	reverse voltage		-	-	20	V
I _F	forward current		-	-	1	А
V _F	forward voltage	I _F = 1 A	<u>[1]</u>	480	550	mV



Medium power Schottky barrier single diode

2. Pinning information

Table 2.	Pinning		
Pin	Description	Simplified outlin	ne Graphic symbol
1	cathode	[1]	64
2	anode		1 🕂 2
			sym001

[1] The marking bar indicates the cathode.

3. Ordering information

Table 3. Ordering information					
Type number	Package				
	Name	Description	Version		
BAT760	SC-76	plastic surface-mounted package; 2 leads	SOD323		

4. Marking

Table 4. Marking codes	
Type number	Marking code
BAT760	A4

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

		0,	,		
Symbol	Parameter	Conditions	Min	Max	Unit
V _R	reverse voltage		-	20	V
I _F	forward current		-	1	А
I _{FSM}	non-repetitive peak forward current	t _p = 8.3 ms; half-sine wave; JEDEC method	-	5	A
Tj	junction temperature		-	125	°C
T _{amb}	ambient temperature		-65	+125	°C
T _{stg}	storage temperature		-65	+150	°C

Medium power Schottky barrier single diode

6. Thermal characteristics

Table 6.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	hermal resistance from in free air				
			<u>[1]</u> _	-	220	K/W
			[2]	-	180	K/W

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for cathode 10×10 mm².

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 40×40 mm².

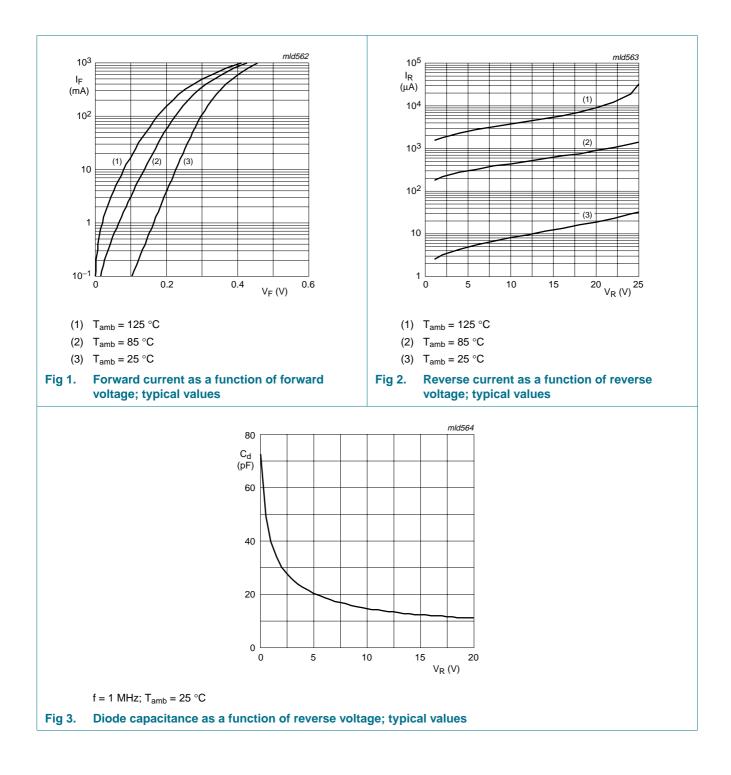
7. Characteristics

Table 7.Characteristics

 $T_{amb} = 25 \circ C$ unless otherwise specified.

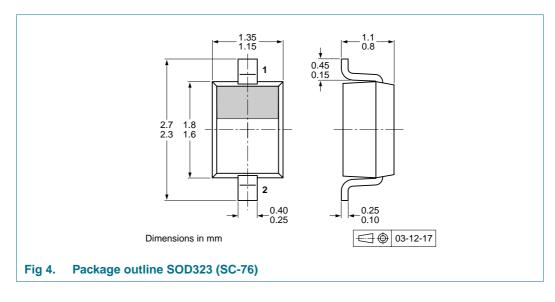
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
VF	forward voltage		<u>[1]</u>			
		I _F = 10 mA	-	240	270	mV
		I _F = 100 mA	-	300	350	mV
		I _F = 1 A	-	480	550	mV
I _R	reverse current		<u>[1]</u>			
		V _R = 5 V	-	5	10	μΑ
		V _R = 8 V	-	7	20	μΑ
		V _R = 15 V	-	10	50	μΑ
C _d	diode capacitance	V _R = 5 V; f = 1 MHz	-	19	25	pF

Medium power Schottky barrier single diode



Medium power Schottky barrier single diode

8. Package outline



9. Packing information

Table 8. Packing methods

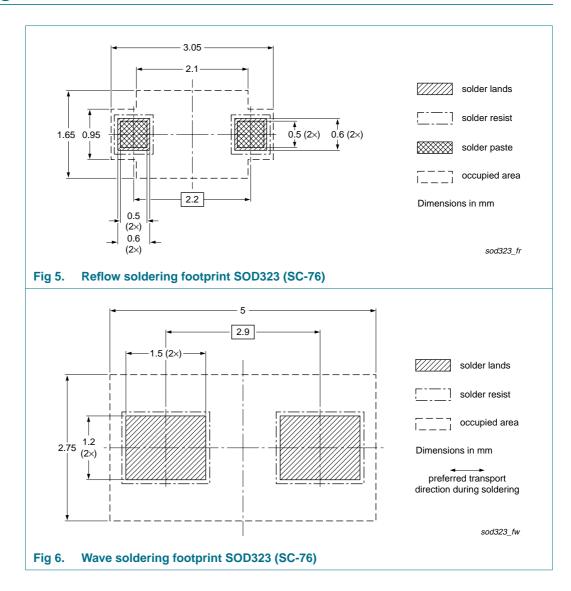
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity	
			3000	10000
BAT760	SOD323	4 mm pitch, 8 mm tape and reel	-115	-135

[1] For further information and the availability of packing methods, see Section 13.

Medium power Schottky barrier single diode

10. Soldering



Medium power Schottky barrier single diode

11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAT760_3	20081017	Product data sheet	-	BAT760_2
Modifications:		of this data sheet has been of NXP Semiconductors.	redesigned to comply	with the new identity
	 Legal texts 	have been adapted to the r	new company name w	here appropriate.
	Table 1 "Qu	iick reference data": added		
	• Figure 4: s	uperseded by minimized pa	ckage outline drawing	
	Section 9 "	Packing information": added	1	
	Section 10	"Soldering": added		
	Section 12	"Legal information": update	d	
BAT760_2	20040126	Product specification	-	BAT760_1
BAT760 1	20010312	Product specification	-	-

Medium power Schottky barrier single diode

12. Legal information

12.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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Medium power Schottky barrier single diode

14. Contents

1	Product profile 1	
1.1	General description 1	
1.2	Features	
1.3	Applications 1	
1.4	Quick reference data 1	
2	Pinning information 2	2
3	Ordering information 2	2
4	Marking 2	2
5	Limiting values 2	2
6	Thermal characteristics 3	3
7	Characteristics 3	3
8	Package outline 5	5
9	Packing information	5
10	Soldering 6	5
11	Revision history 7	7
12	Legal information 8	3
12.1	Data sheet status 8	3
12.2	Definitions 8	3
12.3	Disclaimers	
12.4	Trademarks 8	3
13	Contact information 8	3
14	Contents 9)

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